

General purpose transistor (isolated transistor and diode)

FML9

A 2SB1689 and a RB461F are housed independently in a UMT package.

●Applications

DC / DC converter
Motor driver

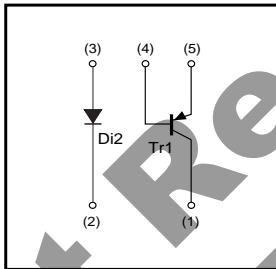
●Features

- 1) Tr : Low $V_{CE(sat)}$
Di : Low V_f
- 2) Small package

●Structure

Silicon epitaxial planar transistor
Schottky barrier diode

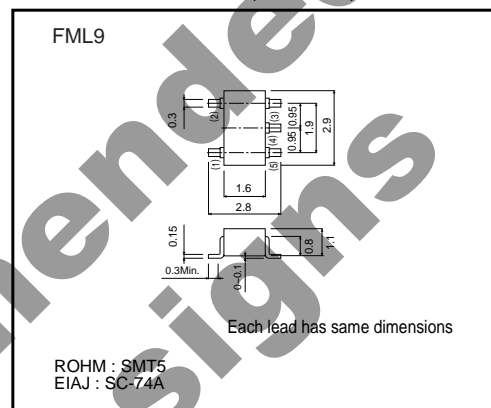
●Equivalent circuit



●Packaging specifications

| | |
|-----------------------------|------|
| Type | FML9 |
| Package | SMT5 |
| Marking | L9 |
| Code | TR |
| Basic ordering unit(pieces) | 3000 |

●External dimensions (Unit : mm)



Transistors

●Absolute maximum ratings (Ta=25°C)

Tr1

| Parameter | Symbol | Limits | Unit |
|------------------------------|------------------|-------------|-------|
| Collector-base voltage | V _{CB0} | -15 | V |
| Collector-emitter voltage | V _{CEO} | -12 | V |
| Emitter-base voltage | V _{EBO} | -6 | V |
| Collector current | I _c | -1.5 | A |
| | I _{CP} | -3 | A *1 |
| Power dissipation | P _c | 200 | mW *2 |
| Junction temperature | T _j | 150 | °C |
| Range of storage temperature | T _{stg} | -40 to +125 | °C |

*1 Single pulse, P_w=1ms.

*2 Each terminal mounted on a recommended land.

Di2

| Parameter | Symbol | Limits | Unit |
|---------------------------------------|------------------|-------------|------|
| Peak reverse voltage | V _{RM} | 25 | V |
| Average rectified forward current | I _F | 700 | mA |
| Forward current surge peak (60Hz, 1∞) | I _{FSM} | 3 | A |
| Reverse voltage (DC) | V _R | 20 | V |
| Junction temperature | T _j | 125 | °C |
| Range of storage temperature | T _{stg} | -40 to +125 | °C |

●Electrical characteristics (Ta=25°C)

Tr1

| Parameter | Symbol | Min. | Typ. | Max. | Unit | Conditions |
|--------------------------------------|----------------------|------|------|------|------|---|
| Collector-emitter breakdown voltage | BV _{CEO} | -12 | - | - | V | I _c =-1mA |
| Collector-base breakdown voltage | BV _{CB0} | -15 | - | - | V | I _c =-10μA |
| Emitter-base breakdown voltage | BV _{EBO} | -6 | - | - | V | I _E =-10μA |
| Collector cut-off current | I _{CB0} | - | - | -100 | nA | V _{CB} =-15V |
| Emitter cut-off current | I _{EBO} | - | - | -100 | nA | V _{EB} =-6V |
| Collector-emitter saturation voltage | V _{CE(sat)} | - | -110 | -200 | mV | I _c =-500mA, I _B =-25mA |
| DC current gain | h _{FE} | 270 | - | 680 | - | V _{CE} =-2V, I _c =-200mA |
| Transition frequency | f _T | - | 400 | - | MHz | V _{CE} =-2V, I _E =200mA, f=100MHz |
| Collector output capacitance | C _{ob} | - | 12 | - | pF | V _{CB} =-10V, I _E =0mA, f=1MHz |

Di2

| Parameter | Symbol | Min. | Typ. | Max. | Unit | Conditions |
|-----------------|----------------|------|------|------|------|-----------------------|
| Forward voltage | V _F | - | - | 490 | mV | I _F =700mA |
| Reverse current | I _R | - | - | 200 | μA | V _R =20V |

Transistors

●Electrical characteristic curves

Tr1

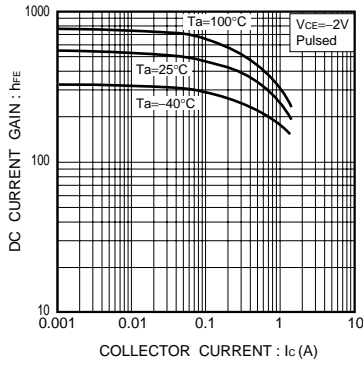


Fig.1 DC current gain vs. collector current

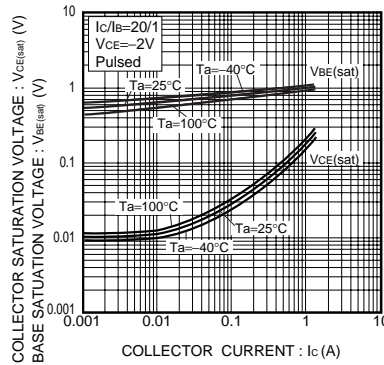


Fig.2 Base-emitter saturation voltage vs. collector current

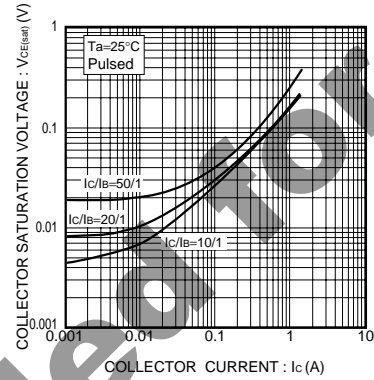


Fig.3 Collector-emitter saturation voltage vs. collector current

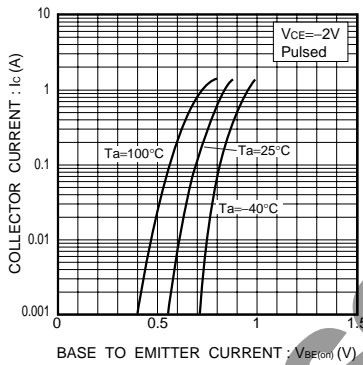


Fig.4 Grounded emitter propagation characteristics

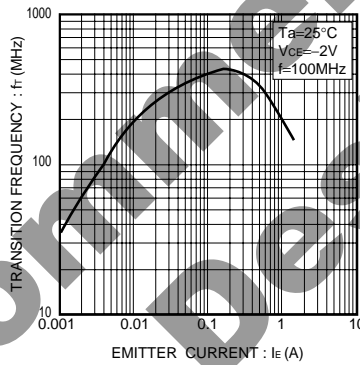


Fig.5 Gain bandwidth product vs. emitter current

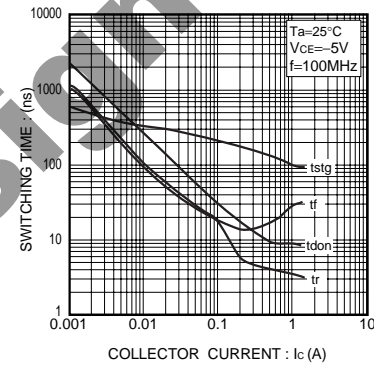


Fig.6 Switching time

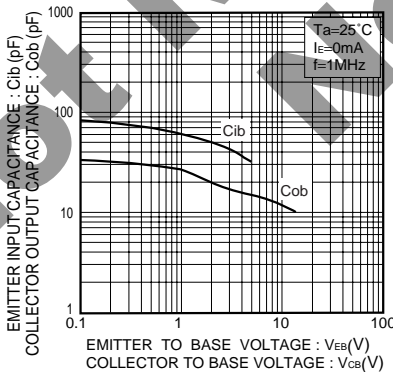


Fig.7 Collector output capacitance vs. collector-base voltage
Emitter input capacitance vs. emitter-base voltage

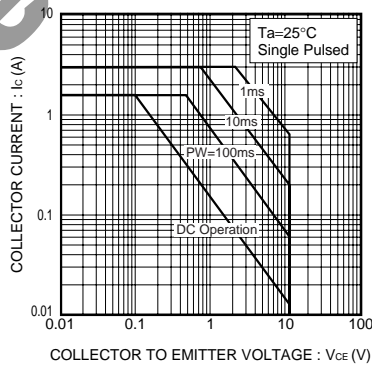


Fig.8 Safe operation area

Transistors

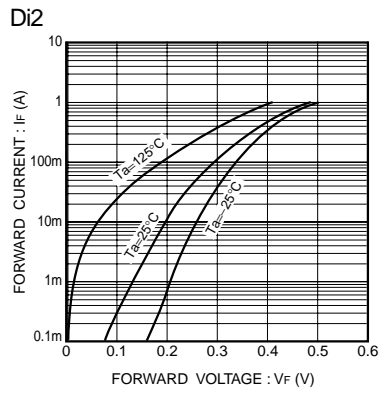


Fig.9 Forward characteristics

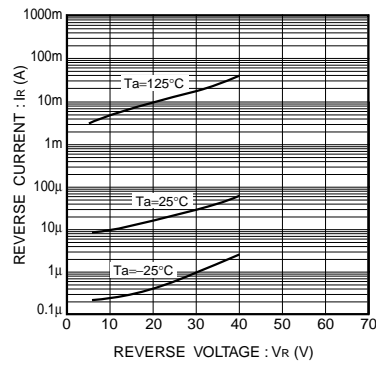


Fig.10 Reverse characteristics

Not Recommended for New Designs

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